

# Combinatorial Pulsed Laser Deposition System



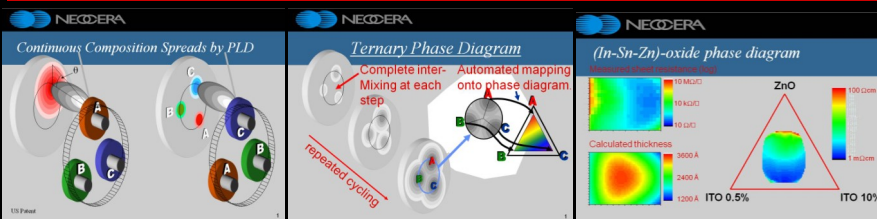
- Stand-alone turn-key combinatorial PLD System.
- Continuous Composition Spreads of binary/ternary/quaternary phase spreads.
- No post anneal and no masks.
- Film growth under 'true' deposition conditions (such as 800°C, 500mTorr).
- Wafer size: 2" diameter is standard (with 4" and 6" custom designs).
- Deposition of epitaxial films, multilayer heterostructures and Superlattices.
- Oxygen compatibility for oxide film depositions at high temperatures.



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# Combinatorial PLD /Continuous Composition Spreads

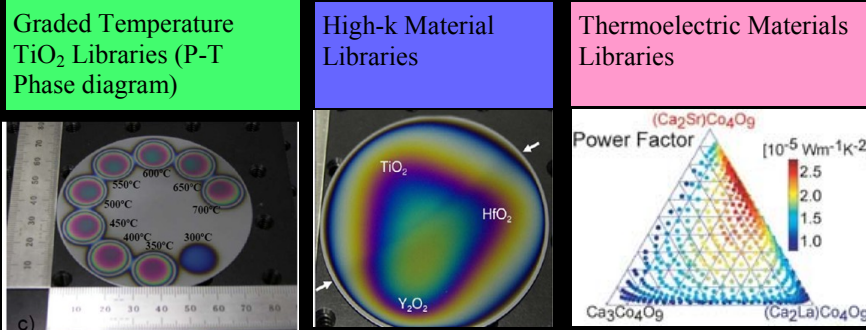
The ability to produce many different material compositions in a single deposition run greatly accelerates the time to arrive at an optimum composition having the desired material properties. Continuous Composition Spread PLD (CCS-PLD) is based on the deposition rate profiles naturally occurring in PLD as a result of the  $\cos^n\theta$  ( $5 \leq n \leq 11$ ) dependence. PLD-CCS benefits from the proven ease of multilayer depositions using Neocera software and the intrinsic forward-directed nature of the PLD process to vary the composition of a binary/ternary/quaternary phase spread. PLD-CCS varies the material in an analog scheme, rather than in discrete elements, thus eliminating the need for masks. This allows for a very rapid successive deposition of each constituent at a rate of much less than a monolayer per cycle, resulting in an approach that is fundamentally equivalent to a co-deposition method. The fact that this method does not depend on a post-deposition anneal to promote inter-diffusion or crystallization makes it applicable to studies where growth temperature is a critical parameter, or to situations where high-temperature anneals are incompatible with either the deposited material or the substrate. As no masks are used, this technique can operate in a wide dynamic range of pressures (up to about 500 mTorr) which are typically not possible in a mask-based approach. Neocera PLD systems can provide both combinatorial PLD (CCS-PLD) and standard PLD capabilities within the same system.



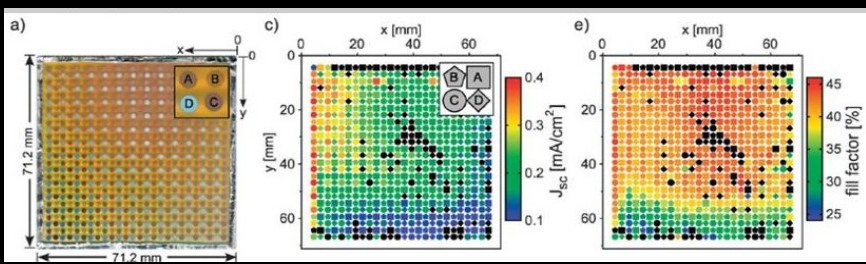
## Combinatorial PLD System Specifications

Feature	Details
1. Substrate sizes	2" diameter standard. 4" and 6" on request.
2. PLD Chamber size	12" or 18" diameter Spherical chamber.
3. Base vacuum	$5 \times 10^{-7}$ Torr Standard $5 \times 10^{-9}$ Torr (upgrade)
4. Substrate heating	850°C (2" and 4" wafers) 750°C (6" wafers)
5. Target Carousel	6x 1" diameter
6. Process gases	O <sub>2</sub> , N <sub>2</sub> , Ar, (MFC controlled)
7. Substrate-Masks	Only for 1 cm x 1 cm size substrates
8. Load-locks	For Substrate.
9. Automation	Windows 7, LabView 2013

(Below) P. K. Schenck et al, *Thin Solid Films S17(2008)*, 691-694/ **Pioneer 180 Combinatorial PLD System**, NIST, Gaithersburg, MD, USA.



(Below) Solar cell libraries for the investigation of different metal back-contacts for TiO<sub>2</sub>-Cu<sub>2</sub>O hetero-junctions (S. Ruhle et al, *Phys. Chem. Chem. Phys.*, 2014, 16, 7066). **Pioneer 180-PLD System at Bar-Ilan University/Israel.**



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